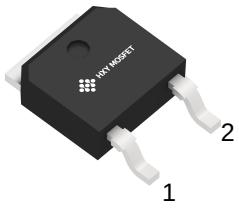
FFSD0865B-F085

Silicon Carbide Schottky Diode

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F



TO-252N-2L

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Part Number	Package	Qty(PCS)
FFSD0865B-F085	TO-252N-2L	2500

Maximum Ratings (T_C = 25 ˚C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	
V_{RSM}	Surge Peak Reverse Voltage	650	V	
I_F	Continuous Forward Current	22.3 10.5 8	A	T_C=25˚C T_C=135˚C T_C=149.5˚C
I_{FRM}	Repetitive Peak Forward Surge Current	30	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	60	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
P_{tot}	Power Dissipation	89 38	W	T_C=25˚C T_C=110˚C
T_J , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	˚C	
$\int i^2dt$	i²dt value	18	A^2s	T_C=25˚C, t_p = 10 ms, Half Sine Wave

Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	650			V	
V_F	Forward Voltage		1.42 1.88	1.7 2.5	V	I_F = 6 A T_J=25°C I_F = 6 A T_J=175°C
I_R	Reverse Current		0.12 0.91	50 100	μA	V_R = 650 V T_J=25°C V_R = 650 V T_J=175°C
Q_C	Total Capacitive Charge		21		nC	V_R = 400 V T_J = 25°C
C	Total Capacitance		395 42 41		pF	V_R = 0 V, T_J = 25°C, f = 1 MHz V_R = 200 V, T_J = 25°C, f = 1 MHz V_R = 400 V, T_J = 25°C, f = 1 MHz
E_C	Capacitance Stored Energy		5		μJ	V_R = 400 V

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.69	°C/W

Typical Performance

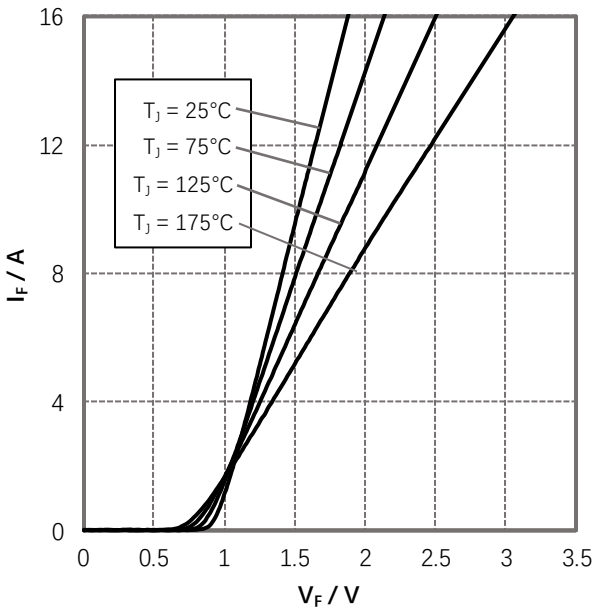


Figure 1. Forward Characteristics

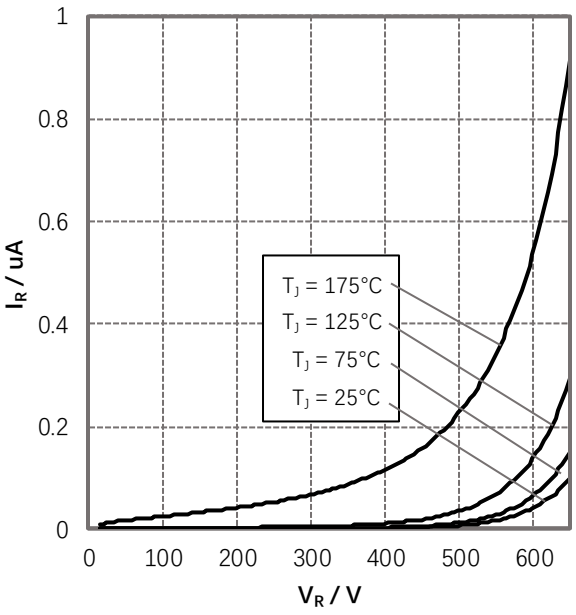


Figure 2. Reverse Characteristics

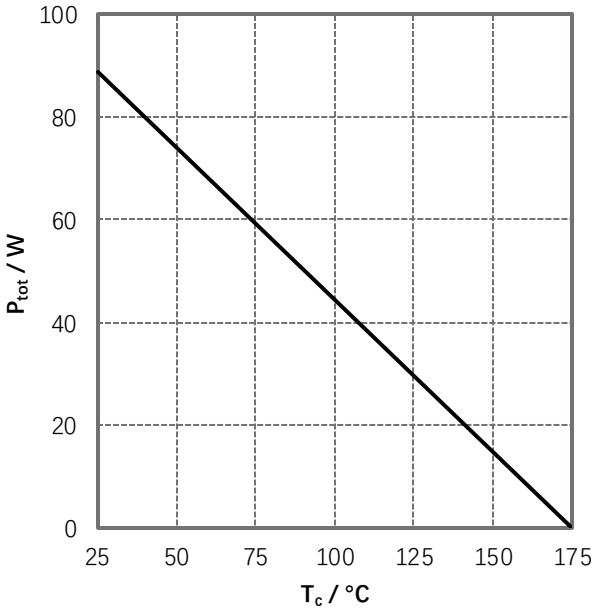


Figure 3. Power Derating

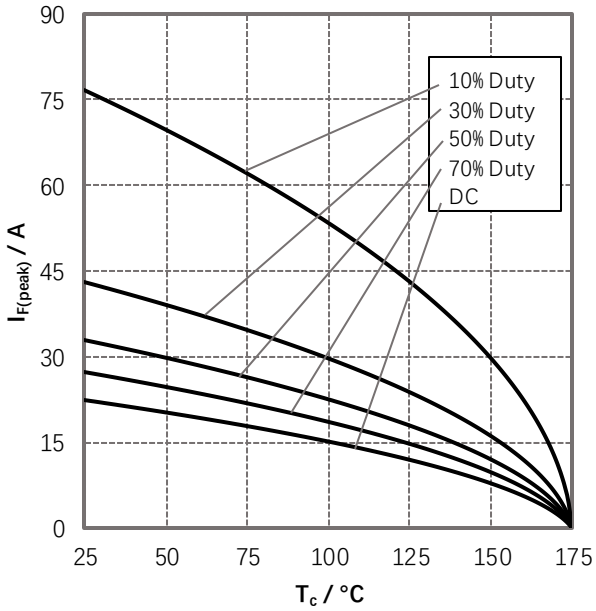


Figure 4. Current Derating

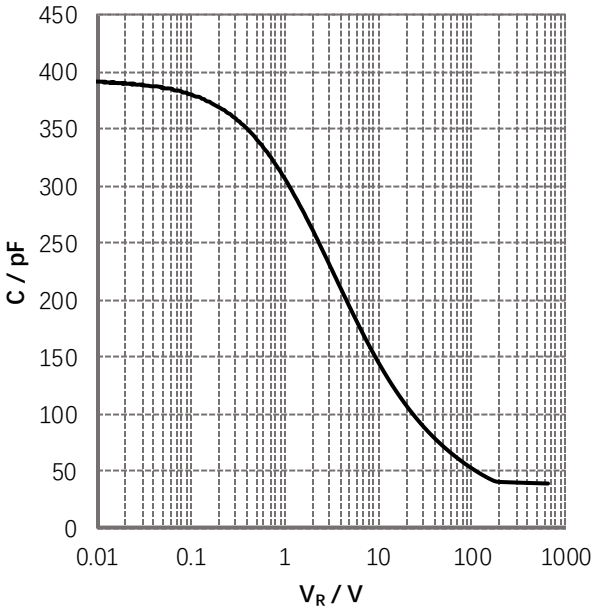


Figure 5. Capacitance vs. Reverse Voltage

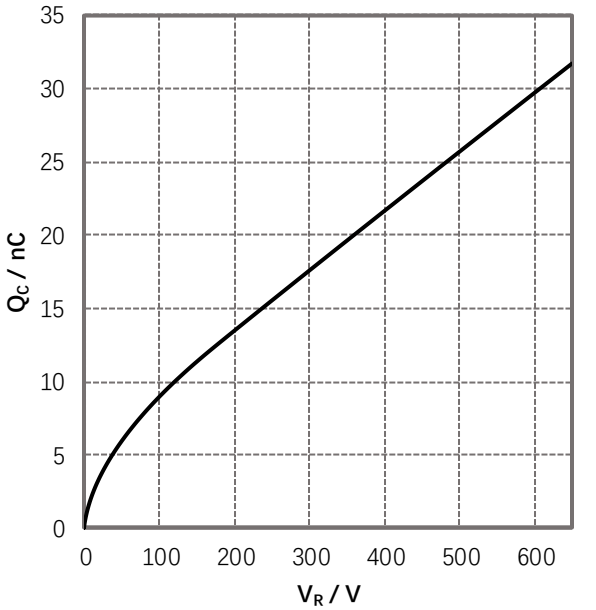


Figure 6. Total Capacitance Charge vs. Reverse Voltage

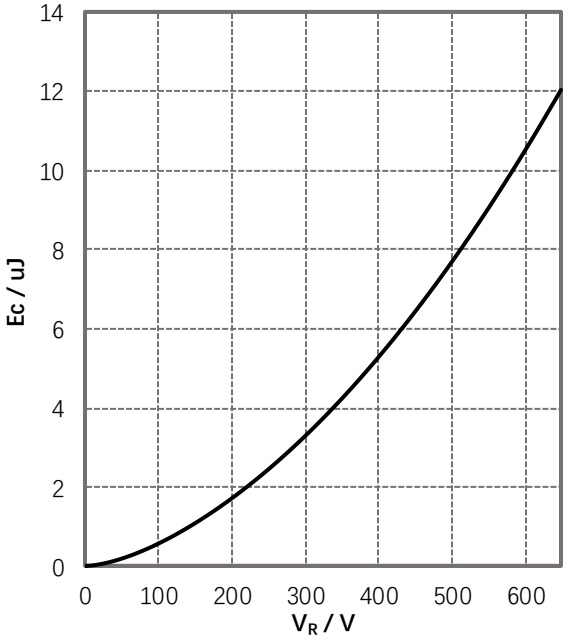


Figure 7. Capacitance Stored Energy

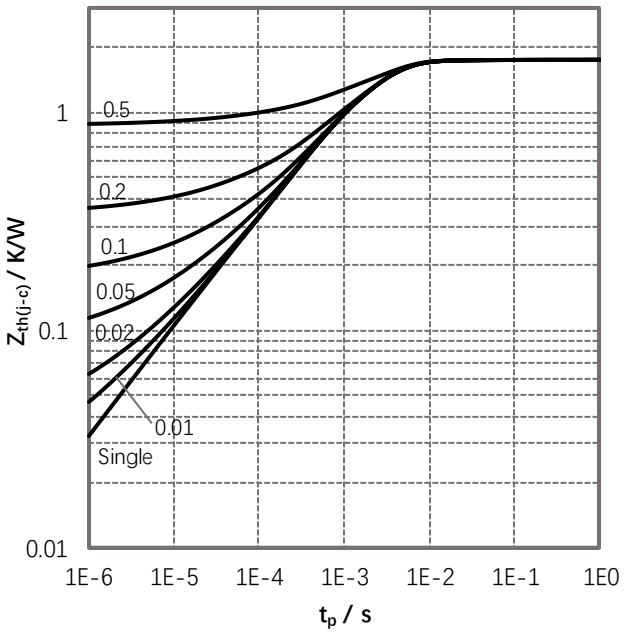
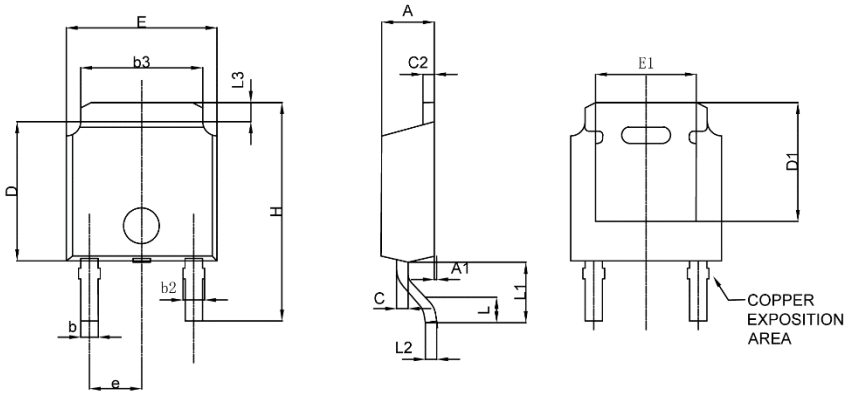


Figure 8. Transient Thermal Impedance

Package Information
TO-252N-2L



Symbol	DIMENSIONAL REQMTS		
	Min	Nom	Max
E	6.35	6.60	6.73
L	1.40	1.52	1.78
L1	2.743REF		
L2	0.508BSC		
L3	0.89	——	1.27
D	5.97	6.10	6.22
H	9.40	10.00	10.40
b	0.64	0.76	0.89
b2	0.76	0.84	1.14
b3	4.95	5.34	5.46
e	2.286BSC		
A	2.18	2.30	2.39
A1	0.00	——	0.13
c	0.46	0.50	0.61
c2	0.46	0.50	0.60
D1	5.21	——	——
E1	4.32	——	——

Note:
1.All Dimension Are In mm
2.Package Body Sizes Exclude Mold Flash,Protrusion Or Gate Burrs.
Mold Flash,Protrusion Or Gate Burrs Shall Not Exceed 0.10mm Per Side.
3.Package Body Sizes Determined At The Outermost Extremes
Of The Plastic Body Exclusive Of Mold Flash,
Gate Burrs And Interlead Flash,
But Including Any Mismatch Between
The Top And Bottom Of The Plastic Body.
4.The Package Top May Be Smaller Than The Package Bottom.
5.Dimension "b" Does Not Include Dambar Protrusion.
Allowable Dambar Protrusion Shall Be 0.10mm
Total In Excess Of "b" Dimension At Maximun Material Condition.
The Dambar Cannot Be Located On The Lower Radius Of The Foot.

Attention

■ Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.

■ HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.

■ Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

■ HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could
give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

■ In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

■ No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.

■ Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

■ Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.

Unikeyic Electronics

Global Electronic Components Distributor

Click to view pricing, inventory, delivery, and lifecycle information:

HXY MOSFET:

60N06 HCEZ36V,L3F HSEN2411D3 LM393DR-HXY PESDLC2FD3V3BH HESD36VD3B HSG3D15B3.3MA PESDSC2FD5VU PJSD24CW_R1 AQ15C-01FTG AZ4007-01H ESD5LM5.0C-HXY HESDSLC3V3D3B HRCLAMP3371ZCTFT HSTS521050B331 PJEC5V0M1FN2 HAZ4007-01H HSD15C.TCT HSEN3611D3 TPSMB28A-VR BV05C-H HACPDQC5V0-HF HLY323BC1524L PESDNC2XD5VBL AZ4836-01L HPTVSUC3D5VB PESDNC2XD5VBF RLSD32A121V ESD5L5.0C-HXY TPSMB100CA-VR